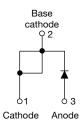


Vishay Semiconductors

Schottky Rectifier, 20 A

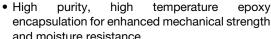


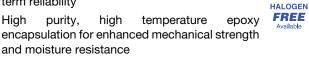


PRODUCT SUMMARY					
Package	TO-220AC				
I _{F(AV)}	20 A				
V_R	15 V				
V _F at I _F	See Electrical table				
I _{RM} max.	600 mA at 100 °C				
T _J max.	125 °C				
Diode variation	Single die				
E _{AS}	10 mJ				

FEATURES

- 125 °C T_J operation (V_R < 5 V)
- · Single diode configuration
- · Optimized for OR-ing applications
- Ultra low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability





- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The Schottky rectifier module has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	20	А			
V _{RRM}		15	V			
I _{FSM}	t _p = 5 μs sine	700	Α			
V _F	19 A _{pk} , T _J = 125 °C (typical)	0.25	V			
T _J	Range	- 55 to 125	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-20L15TPbF	VS-20L15T-N3	UNITS		
Maximum DC reverse voltage	V _R	15	15	V		
Maximum working peak reverse voltage	V_{RWM}	15	15	V		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS	
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 85 °C, rectangular waveform		20		
Maximum peak one cycle non-repetitive surge current		5 μs sine or 3 μs rect. pulse Following any rated load condition and with rated		700	Α	
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	330		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 6 mH		10	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		2	Α	



VS-20L15TPbF, VS-20L15T-N3

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS			MAX.	UNITS
		19 A	T 05 00	-	0.41	V
Forward voltage drop	V _{FM} ⁽¹⁾	40 A	- T _J = 25 °C	-	0.52	
See fig. 1	VFM (1)	19 A	T 105 °C	0.25	0.33	
		40 A	- T _J = 125 °C	0.37	0.50	
Reverse leakage current	. (1)	T _J = 25 °C		-	10	A
See fig. 2	I _{RM} ⁽¹⁾	T _J = 100 °C	V _R = Rated V _R	-	600	mA
Threshold voltage	V _{F(TO)}	T T		0.1	82	V
Forward slope resistance	r _t	ıj=ıjmax.	$T_J = T_J \text{ max.}$			mΩ
Maximum junction capacitance	C _T	V _R = 5 V _{DC} , (test signal rar	-	2000	pF	
Typical series inductance	L _S	Measured lead to lead 5 m	8	-	nH	
Maximum voltage rate of change	dV/dt	Rated V _R	10	000	V/µs	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature range	TJ		- 55 to 125	°C		
Maximum storage temperature range	T _{Stg}		- 50 to 150	C		
Maximum thermal resistance, junction to case	R _{thJC}	R _{thJC} DC operation See fig. 4				
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased (for TO-220)	0.50	°C/W		
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation (for D ² PAK)	40			
Approximate weight			2	g		
Approximate weight			0.07	OZ.		
Mounting torque minimum		Non-lubricated threads	6 (5)	kgf · cm		
Mounting torque — maximum		Non-iublicated tilleaus	12 (10)	(lbf · in)		
Marking device	Case style TO-220AC 20L15T		15T			

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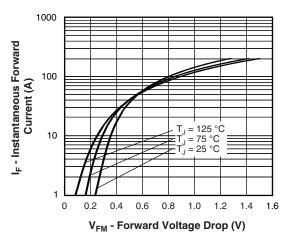


Fig. 1 - Maximum Forward Voltage Drop Characteristics

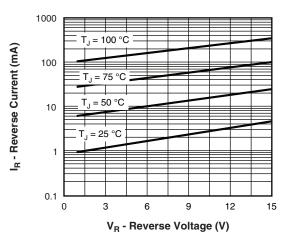


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

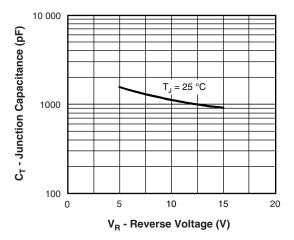


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

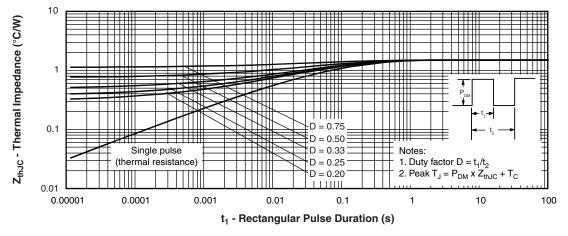


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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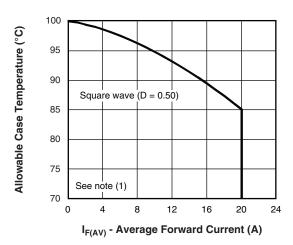


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

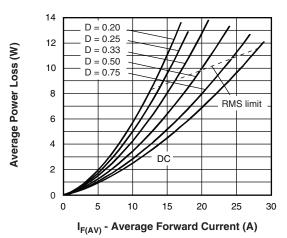


Fig. 6 - Forward Power Loss Characteristics

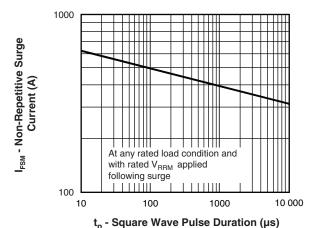


Fig. 7 - Maximum Non-Repetitive Surge Current

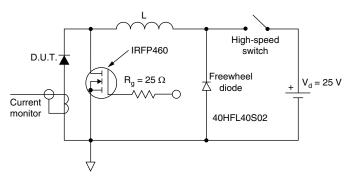


Fig. 8 - Unclamped Inductive Test Circuit

Note

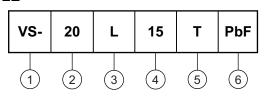
 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

VS-20L15TPbF, VS-20L15T-N3

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Current rating (20 = 20 A)

3 - Schottky "L" series

4 - Voltage code (15 = 15 V)

5 - Package

T = TO-220

6 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-20L15TPbF	50	1000	Antistatic plastic tube			
VS-20L15T-N3	50	1000	Antistatic plastic tube			

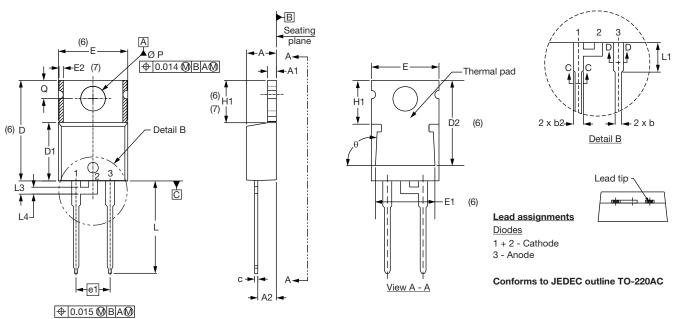
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95221</u>					
Dort marking information	TO-220AC PbF	www.vishay.com/doc?95224			
Part marking information	TO-220AC -N3	www.vishay.com/doc?95068			



Vishay Semiconductors

TO-220AC

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INCHES		NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
Е	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIM	IETERS	INCHES		NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
L3	1.78	2.13	0.070	0.084	
L4	0.76	1.27	0.030	0.050	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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